



#### 2.0A SBR® SUPER BARRIER RECTIFIER **SMA**

#### Product Summary (@ T<sub>A</sub> = +25°C)

V <sub>RRM</sub> (V)	I <sub>O</sub> (A)	V <sub>F(MAX)</sub> (V)	I <sub>R(MAX)</sub> (µA)
40	2	0.55	500

#### **Features and Benefits**

- Low Leakage Current
- Patented Super Barrier Rectifier Technology
- Soft, Fast Switching Capability
- +150°C Operating Junction Temperature
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

### Applications

- **SMPS**
- DC-DC Converter
- Freewheeling Diodes

#### **Mechanical Data**

- Case: SMA
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Lead Free Plating (Matte Tin Finish). Solderable per MIL-STD-202, Method 208 (63)
- Polarity Indicator: Cathode Band
- Weight: 0.064 grams (Approximate)





# **Ordering Information** (Note 4)

Part Number	Case	Packaging
SBR2A40SA-13	SMA	5000/Tape & Reel

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + CI) and <1000ppm antimony compounds.</p>
  4. For packaging details, go to our website at http"//www.diodes.com/products/packages.html.

# **Marking Information**



S Q 4 = Product Type Marking Code D!! = Manufacturer's Code Marking YWW = Date Code Marking Y = Last Digit of Year (ex: 9 for 2009) WW = Week Code (01 - 53)XX = Foundry and Assembly



# Maximum Ratings @T<sub>A</sub> = +25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitance load, derate current by 20%.

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage	V <sub>RRM</sub>		
Working Peak Reverse Voltage	$V_{RWM}$	40	V
DC Blocking Voltage	$V_{RM}$		
Average Rectified Output Current (See Figure 1)	lo	2	Α
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load	I <sub>FSM</sub>	15	Α

#### **Thermal Characteristics**

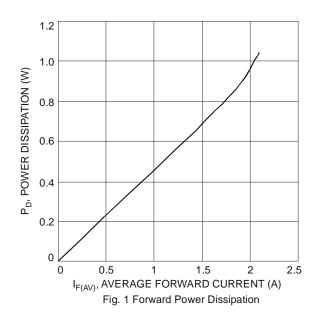
Characteristic	Symbol	Value	Unit
Typical Thermal Resistance Junction to Ambient (Note 5)	$R_{\theta JA}$	110	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-65 to +150	°C

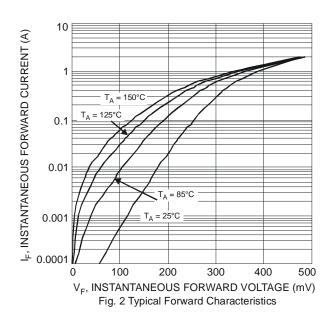
# Electrical Characteristics @T<sub>A</sub> = +25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Forward Voltage Drop	\/_	-	-	0.55	I V	I <sub>F</sub> = 2.0A, T <sub>J</sub> = +25°C
	VF		-	0.50		$I_F = 1.0A, T_J = +25$ °C
Leakage Current (Note 6)	_	-	-	500	μA	V <sub>R</sub> = 40V, T <sub>J</sub> = +25°C
	IR		-	100	mA	$V_R = 40V, T_J = +125$ °C

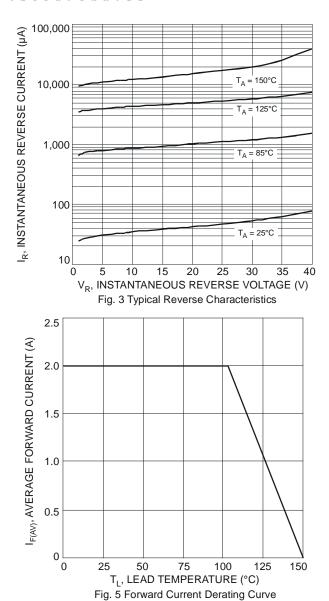
Notes:

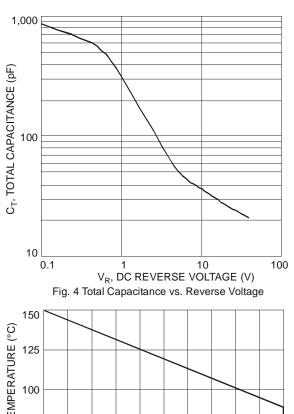
- 5. Device mounted on Polymide substrate, with 1" x 1", 2 oz. Copper, double-sided PCB board.
- 6. Short duration pulse test used to minimize self-heating effect.





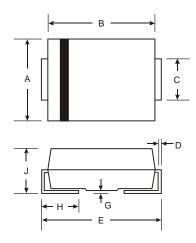






# T<sub>A</sub>, DERATED AMBIENT TEMPERATURE (°C) 75 50 25 0 8 12 16 20 24 28 32 $\rm V_R,\,DC$ REVERSE VOLTAGE (V) 0 Fig. 6 Operating Temperature Derating

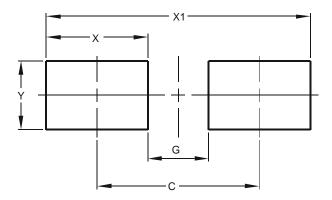
# **Package Outline Dimensions**



Dim         Min         Max           A         2.29         2.92           B         4.00         4.60           C         1.27         1.63           D         0.15         0.31           E         4.80         5.59           G         0.05         0.20           H         0.76         1.52           I         2.01         2.30	SMA			
B 4.00 4.60 C 1.27 1.63 D 0.15 0.31 E 4.80 5.59 G 0.05 0.20 H 0.76 1.52	Dim	Min	Max	
C 1.27 1.63 D 0.15 0.31 E 4.80 5.59 G 0.05 0.20 H 0.76 1.52	Α	2.29	2.92	
D         0.15         0.31           E         4.80         5.59           G         0.05         0.20           H         0.76         1.52	В	4.00	4.60	
E 4.80 5.59 G 0.05 0.20 H 0.76 1.52	C	1.27	1.63	
<b>G</b> 0.05 0.20 <b>H</b> 0.76 1.52	D	0.15	0.31	
<b>H</b> 0.76 1.52	Е	4.80	5.59	
	O	0.05	0.20	
1 2.01 2.30	Н	0.76	1.52	
2.01	۲	2.01	2.30	
All Dimensions in mm				



#### **Suggested Pad Layout**



Dimensions	Value (in mm)
С	4.00
G	1.50
Х	2.50
X1	6.50
Υ	1.70

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